

Dual Switching Diode BAS16DXV6

Features

- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS $(T_A = 25^{\circ}C)$

| Rating | Symbol | Max | Unit |
|---|------------------------|-----|------|
| Continuous Reverse Voltage | V _R | 100 | V |
| Recurrent Peak Forward Current | IF | 200 | mA |
| Peak Forward Surge Current Pulse Width = 10 μs | I _{FM(surge)} | 500 | mA |

THERMAL CHARACTERISTICS

| Characteristic (One Junction Heated) | Symbol | Max | Unit |
|---|-----------------------------------|-------------|-------------|
| Total Device Dissipation (Note 1) T _A = 25°C Derate above 25°C | P _D | 357 2.9 | mW mW/°C |
| Thermal Resistance, Junction-to-Ambient (Note 1) | $R_{\theta JA}$ | 350 | °C/W |
| Characteristic (Both Junctions Heated) | Symbol | Max | Unit |
| Total Device Dissipation (Note 1) T _A = 25°C Derate above 25°C | P _D | 500 4.0 | mW mW/°C |
| Thermal Resistance, Junction-to-Ambient (Note 1) | $R_{\theta JA}$ | 250 | °C/W |
| Junction and Storage Temperature | T _J , T _{stg} | -55 to +150 | °C |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR-4 @ Minimum Pad



SOT-563 CASE 463A PLASTIC



MARKING DIAGRAM



A6 = Specific Device Code

M = Date CodePb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|---------------|----------------------|-----------------------|
| BAS16DXV6T1G | SOT-563 (Pb-Free) | 4000 / Tape & Reel |
| SBAS16DXV6T1G | SOT-563 (Pb-Free) | 4000 / Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

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ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

| Characteristic | Symbol | Min | Max | Unit |
|---|-----------------|------------------|----------------------------|------|
| Forward Voltage $ (I_F = 1.0 \text{ mA}) $ $ (I_F = 10 \text{ mA}) $ $ (I_F = 50 \text{ mA}) $ $ (I_F = 150 \text{ mA}) $ | V _F | - - - - | 715 855 1000 1250 | mV |
| Reverse Current $(V_R = 100 \text{ V})$ $(V_R = 75 \text{ V}, T_J = 150^{\circ}\text{C})$ $(V_R = 25 \text{ V}, T_J = 150^{\circ}\text{C})$ | I _R | - - - | 1.0 50 30 | μΑ |
| Capacitance (V _R = 0, f = 1.0 MHz) | C _D | - | 2.0 | pF |
| Reverse Recovery Time (I _F = I _R = 10 mA, R _L = 50 Ω) (Figure 1) | t _{rr} | _ | 6.0 | ns |
| Stored Charge (I _F = 10 mA to V_R = 6.0 V, R_L = 500 Ω) (Figure 2) | QS | _ | 45 | PC |
| Forward Recovery Voltage ($I_F = 10 \text{ mA}, t_r = 20 \text{ ns}$) (Figure 3) | V _{FR} | _ | 1.75 | V |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

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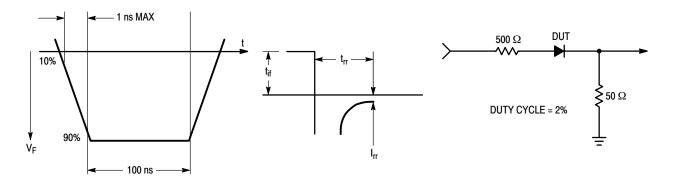


Figure 1. Reverse Recovery Time Equivalent Test Circuit

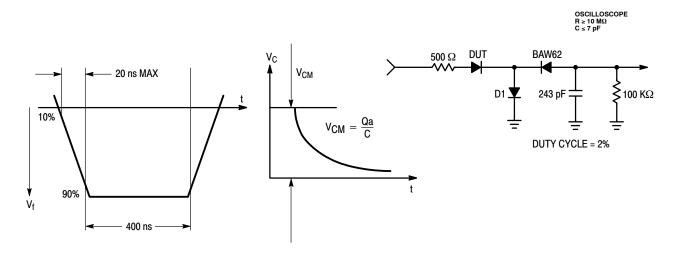


Figure 2. Stored Charge Equivalent Test Circuit

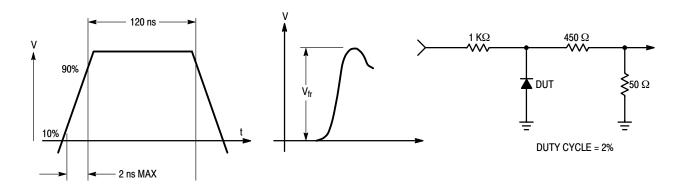
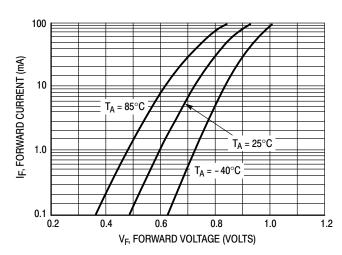


Figure 3. Forward Recovery Voltage Equivalent Test Circuit

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TYPICAL CHARACTERISTICS



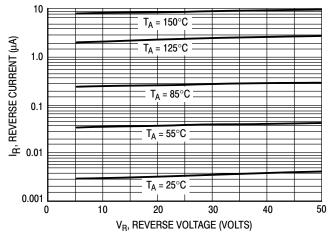


Figure 4. Forward Voltage

Figure 5. Leakage Current

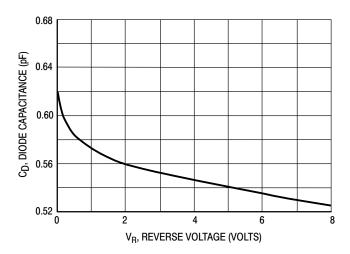


Figure 6. Capacitance

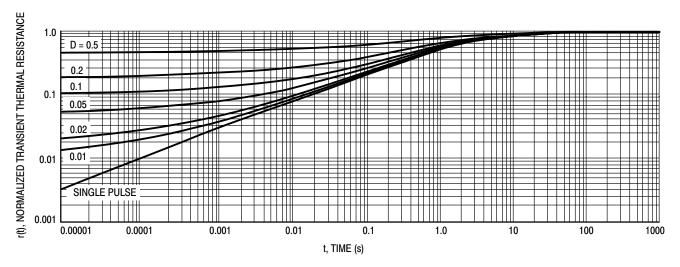


Figure 7. Normalized Thermal Response

MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS



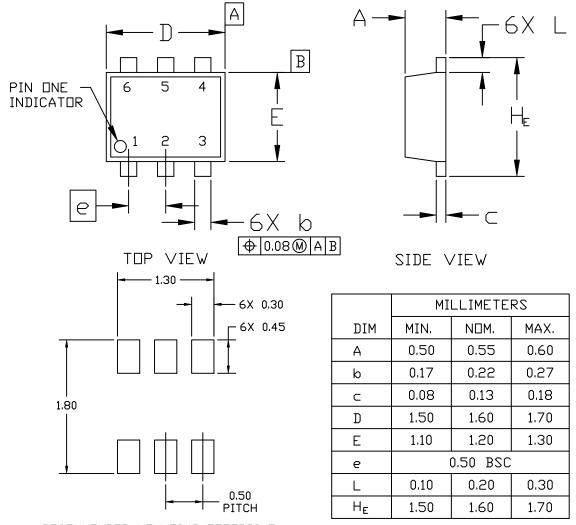


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NOTES:

- I. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.



RECOMMENDED MOUNTING FOOTPRINT*

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

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| STYLE 1: PIN 1. EMITTER 1 2. BASE 1 3. COLLECTOR 2 4. EMITTER 2 5. BASE 2 6. COLLECTOR 1 | STYLE 2: PIN 1. EMITTER 1 2. EMITTER 2 3. BASE 2 4. COLLECTOR 2 5. BASE 1 6. COLLECTOR 1 | STYLE 3: PIN 1. CATHODE 1 2. CATHODE 1 3. ANODE/ANODE 2 4. CATHODE 2 5. CATHODE 2 6. ANODE/ANODE 1 |
|--|--|--|
| STYLE 4: PIN 1. COLLECTOR 2. COLLECTOR 3. BASE 4. EMITTER 5. COLLECTOR 6. COLLECTOR | STYLE 5: PIN 1. CATHODE 2. CATHODE 3. ANODE 4. ANODE 5. CATHODE 6. CATHODE | STYLE 6: PIN 1. CATHODE 2. ANODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE |
| STYLE 7: PIN 1. CATHODE 2. ANODE 3. CATHODE 4. CATHODE 5. ANODE 6. CATHODE | STYLE 8: PIN 1. DRAIN 2. DRAIN 3. GATE 4. SDURCE 5. DRAIN 6. DRAIN | STYLE 9: PIN 1. SDURCE 1 2. GATE 1 3. DRAIN 2 4. SDURCE 2 5. GATE 2 6. DRAIN 1 |
| STYLE 10: PIN 1. CATHODE 1 2. N/C 3. CATHODE 2 4. ANODE 2 5. N/C 6. ANODE 1 | STYLE 11: PIN 1. EMITTER 2 2. BASE 2 3. COLLECTOR 1 4. EMITTER 1 5. BASE 1 6. COLLECTOR 2 | |

GENERIC MARKING DIAGRAM*



XX = Specific Device CodeM = Month Code= Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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